

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# T C 7 W T 1 2 5 F U

# DUAL BUS BUFFER

The TC7WT125FU is a high speed CMOS DUAL BUS BUFFERS fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The input threshold levels are compatible with TTL output voltage.

The require 3-state control input  $\overline{G}$  to be set high to place the output into the high impedance.

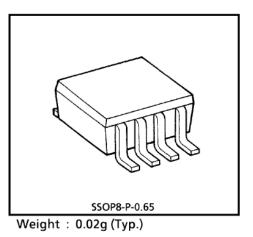
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### FEATURES

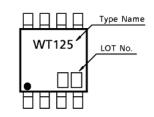
- Low Power Dissipation  $\dots I_{CC} = 2\mu A$  (Max.) at Ta = 25°C
- Compatible with TTL outputs  $\cdots$  V<sub>IL</sub> = 0.8V (Max.), V<sub>IH</sub> = 2.0V (Min.)
- Output Drive Capability ..... 15 LSTTL Loads
- Symmetrical Output Impedance… |IOH| = IOL = 6mA (Min.)

#### MAXIMUM RATINGS (Ta = 25°C)

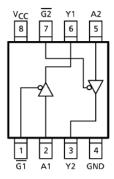
CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	Vcc	-0.5~7	V
DC Input Voltage	VIN	-0.5~V <sub>CC</sub> +0.5	V
DC Output Voltage	Vout	-0.5~V <sub>CC</sub> +0.5	V
Input Diode Current	<sup>I</sup> IK	± 20	mA
Output Diode Current	lок	± 20	mA
DC Output Current	IOUT	± 35	mA
DC V <sub>CC</sub> /Ground Current	lcc	± 37.5	mA
Power Dissipation	PD	300	mW
Storage Temperature	T <sub>stg</sub>	-65~150	°C
Lead Temperature (10 s)	Т	260	°C



MARKING

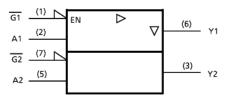


#### PIN ASSIGNMENT (TOP VIEW)



# **TOSHIBA**

#### LOGIC DIAGRAM



#### TRUTH TABLE

INP	UTS	OUTPUTS		
G	Α	Y		
Н	×	Z		
L	L	L		
L	Н	Н		

x : Don't Care

Z : High Impedance

#### **RECOMMENDED OPERATING CONDITIONS**

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	Vcc	4.5~5.5	V
Input Voltage	VIN	0~V <sub>CC</sub>	V
Output Voltage	VOUT	0~V <sub>CC</sub>	V
Operating Temperature	T <sub>opr</sub>	- 40~85	°C
Input Rise and Fall Time	t <sub>r</sub> , t <sub>f</sub>	0~500	ns

#### DC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC		SYMBOL TEST CONDITION		Vcc	1	a = 25°(	2	Ta = −40~85°C		UNIT	
CHARACTERISTIC	STIVIDUL			(V)	MIN.	TYP.	MAX.	MIN.	MAX.		
High-Level	V			4.5~	2.0			2.0		v	
Input Voltage	VIH			5.5	2.0	_	_	2.0		Ň	
Low-Level	Vu			4.5~			0.8		0.8	v	
Input Voltage	VIL			5.5		_	0.0		0.0	Ň	
High-Level	Vall	$V_{IN} = V_{IH}$	l <sub>OH</sub> = -20μA	4.5	4.4	4.5	—	4.4	—	v	
Output Voltage	∨он	or V <sub>IL</sub>	I <sub>OH</sub> = - 6mA	4.5	4.18	4.31	—	4.13	—	v	
Low-Level	Max	Mar Mar		4.5	_	0.0	0.10	—	0.10	v	
Output Voltage	VOL	$V_{IN} = V_{IL}$		4.5	_	0.17	0.26	—	0.33		
3-State Output	107	$V_{IN} = = V_{IH}$ or $V_{IL}$ $V_{OUT} = V_{CC}$ or GND		5.5	-	-	±0.5	-	± 5.0	μΑ	
Off-State Current	loz										
Input Leakage	lusi	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5			±0.1		±1.0	μA	
Current	IN			5.5			20.1		1.0	μΑ	
	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	—	—	2.0	—	20.0	μA	
Quiescent Supply		PER INPUT	: V <sub>IN</sub> = 0.5V								
Current	Ісст		or 2.4V	5.5	—	_	2.0	_	2.9	mΑ	
		OTHER INPL	JT: V <sub>CC</sub> or GND								

CHARACTERISTIC	SVMPOL	TEST CO	NDITION		Ta = 25°C			Ta = −40~85°C		
	SYMBOL		CL	Vcc	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
Output Transition	t <sub>TLH</sub>		50	4.5	—	7	12	—	15	ns
Time	tTHL	_	50	5.5	—	6	11	—	14	
		_	50	4.5	—	15	25	_	31	ns
Propagation Delay	<sup>t</sup> pLH			5.5	—	13	22	—	28	
Time	tpHL		150	4.5	—	21	33	—	41	
	1.			5.5	—	18	29	—	37	
Output Enable Time		$R_L = 1k\Omega$	50 150	4.5	—	17	30	—	38	ns
	t <sub>pZL</sub>			5.5	—	14	27	—	34	
	<sup>t</sup> pZL tpZH			4.5	—	23	38	—	48	
	· · ·			5.5	—	20	34	_	43	
Output Disable Time	<sup>t</sup> pLZ	$R_L = 1k\Omega$	50	4.5	—	16	30	_	38	
	tpHZ			5.5	—	13	27	—	34	ns
Input Capacitance	CIN	_	_	—	—	5	10	—	10	рF
Output Capacitance	COUT	_	_	—	—	10	—	-	—	рF
Power Dissipation Capacitance	C <sub>PD</sub>	(Note 1)		_	_	32	_	_	_	pF

### AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 6ns$ )

(Note 1) : C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

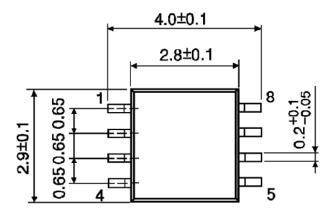
Average operating current can be obtained by the equation :

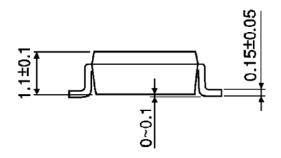
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 2$  (per Gate)



# PACKAGE DIMENSIONS

SSOP8-P-0.65





Weight : 0.02g (Typ.)

Unit : mm

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20070701-EN GENERAL

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